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Understanding [Embedded - Microprocessors](#)

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Product Status	Obsolete
Core Processor	ARM7TDMI
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	90MHz
Co-Processors/DSP	-
RAM Controllers	SDRAM
Graphics Acceleration	No
Display & Interface Controllers	Keypad, LCD, Touchscreen
Ethernet	-
SATA	-
USB	-
Voltage - I/O	2.5V, 2.7V, 3.0V, 3.3V
Operating Temperature	-40°C ~ 85°C (TA)
Security Features	Hardware ID
Package / Case	204-TFBGA
Supplier Device Package	204-TFBGA (13x13)
Purchase URL	https://www.e-xfl.com/product-detail/cirrus-logic/ep7312-ir-90

FEATURES (cont)

- 48 KBytes of on-chip SRAM
- MaverickKey™ IDs
 - 32-bit unique ID can be used for DRM compliance
 - 128-bit random ID
- Available in 74 and 90 MHz clock speeds
- LCD controller
 - Interfaces directly to a single-scan panel monochrome STN LCD
 - Interfaces to a single-scan panel color STN LCD with minimal external glue logic
- Full JTAG boundary scan and Embedded ICE® support
- Integrated Peripheral Interfaces
 - 32-bit SDRAM Interface up to 2 external banks
 - 8/32/16-bit SRAM/FLASH/ROM Interface
 - Digital Audio Interface providing glueless interface to low-power DACs, ADCs and CODECs
 - Two Synchronous Serial Interfaces (SSI1, SSI2)
 - CODEC Sound Interface
 - 8x8 Keypad Scanner
- 27 General Purpose Input/Output pins
- Dedicated LED flasher pin from the RTC
- Internal Peripherals
 - Two 16550 compatible UARTs
 - IrDA Interface
 - Two PWM Interfaces
 - Real-time Clock
 - Two general purpose 16-bit timers
 - Interrupt Controller
 - Boot ROM
- Package
 - 208-Pin LQFP
 - 256-Ball PBGA
 - 204-Ball TFBGA
- The fully static EP7312 is optimized for low power dissipation and is fabricated on a 0.25 micron CMOS process

OVERVIEW (cont.)

The EP7312 is designed for ultra-low-power operation. Its core operates at only 2.5 V, while its I/O has an operation range of 2.5 V–3.3 V. The device has three basic power states: operating, idle and standby.

MaverickKey unique hardware programmed IDs are a solution to the growing concern over secure web content and commerce. With Internet security playing an important role in the delivery of digital media such as books or music, traditional software methods are quickly becoming unreliable. The MaverickKey unique IDs provide OEMs with a method of utilizing specific hardware IDs such as those assigned for SDMI (Secure Digital Music Initiative) or any other authentication mechanism.

The EP7312 integrates an interface to enable a direct connection to many low cost, low power, high quality audio converters. In particular, high quality ADCs, DACs, or CODECs such as the Cirrus Logic CS53L32A, CS43L42, and CS42L50 are easily added to an EP73xx design via the DAI. Some of these devices feature digital bass and treble boost, digital volume control and compressor-limiter functions.

Simply by adding desired memory and peripherals to the highly integrated EP7312 completes a low-power system solution. All necessary interface logic is integrated on-chip.

DC-to-DC Converter Interface (PWM)

- Provides two 96 kHz clock outputs with programmable duty ratio (from 1-in-16 to 15-in-16) that can be used to drive a positive or negative DC to DC converter

Table 14 shows the DC-to-DC Converter Interface pin assignments.

Table 14. DC-to-DC Converter Interface Pin Assignments

Pin Mnemonic	I/O	Pin Description
DRIVE[1:0]	I/O	PWM drive output
FB[1:0]	I	PWM feedback input

Timers

- Internal (RTC) timer
- Two internal 16-bit programmable hardware count-down timers

General Purpose Input/Output (GPIO)

- Three 8-bit and one 3-bit GPIO ports
- Supports scanning keyboard matrix

Table 15 shows the GPIO pin assignments.

Table 15. General Purpose Input/Output Pin Assignments

Pin Mnemonic	I/O	Pin Description
PA[7:0]	I	GPIO port A
PB[7:0]	I	GPIO port B
PD[0]/LEDFLSH (Note)	I/O	GPIO port D
PD[5:1]	I/O	GPIO port D
PD[7:6]/SDQM[1:0] (Note)	I/O	GPIO port D
PE[1:0]/BOOTSEL[1:0] (Note)	I	GPIO port E
PE[2]/CLKSEL (Note)	I	GPIO port E

Note: Pins are multiplexed. See Table 19 on page 11 for more information.

Hardware Debug Interface

- Full JTAG boundary scan and Embedded ICE[®] support

Table 16 shows the Hardware Debug Interface pin assignments.

Table 16. Hardware Debug Interface Pin Assignments

Pin Mnemonic	I/O	Pin Description
TCLK	I	JTAG clock
TDI	I	JTAG data input
TDO	O	JTAG data output
nTRST	I	JTAG async reset input
TMS	I	JTAG mode select

LED Flasher

A dedicated LED flasher module can be used to generate a low frequency signal on Port D pin 0 for the purpose of blinking an LED without CPU intervention. The LED flasher feature is ideal as a visual annunciator in battery powered applications, such as a voice mail indicator on a portable phone or an appointment reminder on a PDA. Table 17 shows the LED Flasher pin assignments.

- Software adjustable flash period and duty cycle
- Operates from 32 kHz RTC clock
- Will continue to flash in IDLE and STANDBY states
- 4 mA drive current

Table 17. LED Flasher Pin Assignments

Pin Mnemonic	I/O	Pin Description
PD[0]/LEDFLSH (Note)	O	LED flasher driver

Note: Pins are multiplexed. See Table 19 on page 11 for more information.

Internal Boot ROM

The internal 128-byte Boot ROM facilitates download of saved code to the on-board SRAM/FLASH.

Packaging

The EP7312 is available in a 208-pin LQFP package, 256-ball PBGA package, or a 204-ball TFBGA package.

Pin Multiplexing

Table 18 shows the pin multiplexing of the DAI, SSI2 and the CODEC. The selection between SSI2 and the CODEC is controlled by the state of the SERSEL bit in SYSCON2. The choice between the SSI2, CODEC, and the DAI is controlled by the DAISEL bit in SYSCON3 (see the *EP7312 User's Manual* for more information).

Table 18. DAI/SSI2/CODEC Pin Multiplexing

Pin Mnemonic	I/O	DAI	SSI2	CODEC
SSICLK	I/O	SCLK	SSICLK	PCMCLK
SSITXDA	O	SDOUT	SSITXDA	PCMOUT
SSIRXDA	I	SDIN	SSIRXDA	PCMIN
SSITXFR	I/O	LRCK	SSITXFR	PCMSYNC
SSIRXFR	I	MCLKIN	SSIRXFR	p/u
BUZ	O	MCLKOUT		

Table 19 shows the pins that have been multiplexed in the EP7312.

Table 19. Pin Multiplexing

Signal	Block	Signal	Block
nMOE	Static Memory	nSDCAS	SDRAM
nMWE	Static Memory	nSDWE	SDRAM
WRITE	Static Memory	nSDRAS	SDRAM
A[27:15]	Static Memory	DRA[0:12]	SDRAM
A[14:13]	Static Memory	DRA[13:14]	SDRAM
PD[7:6]	GPIO	SDQM[1:0]	SDRAM
RUN	System Configuration	CLKEN	System Configuration
nMEDCHG	Interrupt Controller	nBROM	Boot ROM select
PD[0]	GPIO	LEDFLSH	LED Flasher
PE[1:0]	GPIO	BOOTSEL[1:0]	System Configuration
PE[2]	GPIO	CLKSEL	System Configuration

System Design

As shown in system block diagram, simply adding desired memory and peripherals to the highly integrated

EP7312 completes a low-power system solution. All necessary interface logic is integrated on-chip.

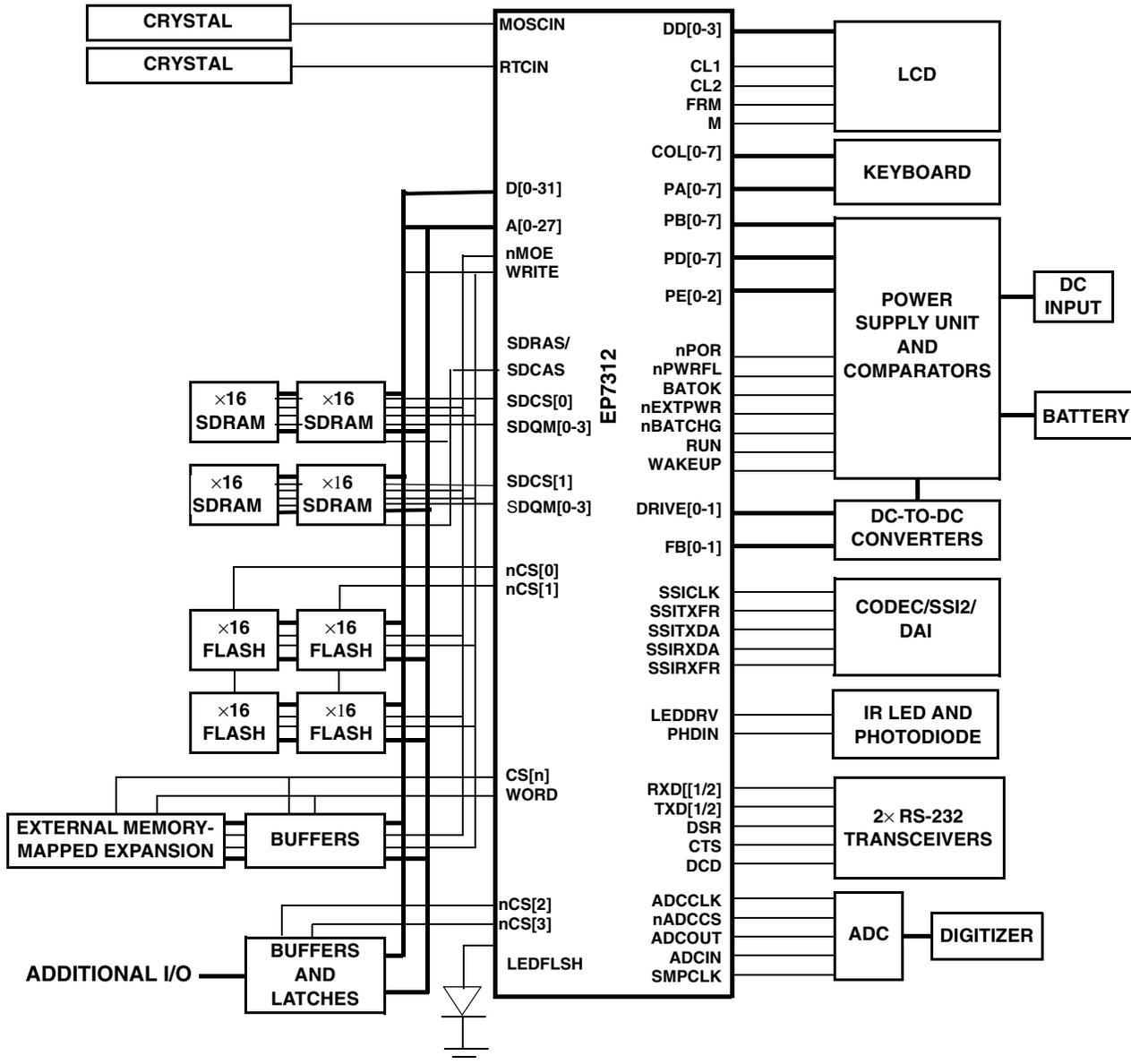


Figure 1. A Fully-Configured EP7312-Based System

Note: A system can only use one of the following peripheral interfaces at any given time: SSI2, CODEC or DAI.

SDRAM Interface

Figure 3 through Figure 6 define the timings associated with all phases of the SDRAM. The following table contains the values for the timings of each of the SDRAM modes.

Parameter	Symbol	Min	Typ	Max	Unit
SDCLK rising edge to SDCS assert delay time	t_{CSa}	0	2	4	ns
SDCLK rising edge to SDCS deassert delay time	t_{CSd}	-3	2	10	ns
SDCLK rising edge to SDRAS assert delay time	t_{RAa}	1	3	7	ns
SDCLK rising edge to SDRAS deassert delay time	t_{RAd}	-3	1	10	ns
SDCLK rising edge to SDRAS invalid delay time	t_{RAnv}	2	4	7	ns
SDCLK rising edge to SDCAS assert delay time	t_{CAa}	-2	2	5	ns
SDCLK rising edge to SDCAS deassert delay time	t_{CAd}	-5	0	3	ns
SDCLK rising edge to ADDR transition time	t_{ADv}	-3	1	5	ns
SDCLK rising edge to ADDR invalid delay time	t_{ADx}	-2	2	5	ns
SDCLK rising edge to SDMWE assert delay time	t_{MWa}	-2	1	5	ns
SDCLK rising edge to SDMWE deassert delay time	t_{MWd}	-4	0	4	ns
DATA transition to SDCLK rising edge time	t_{DAs}	-	-	2	ns
SDCLK rising edge to DATA transition hold time	t_{DAh}	-	-	1	ns
SDCLK rising edge to DATA transition delay time	t_{DAd}	0	-	15	ns

Static Memory Burst Read Cycle

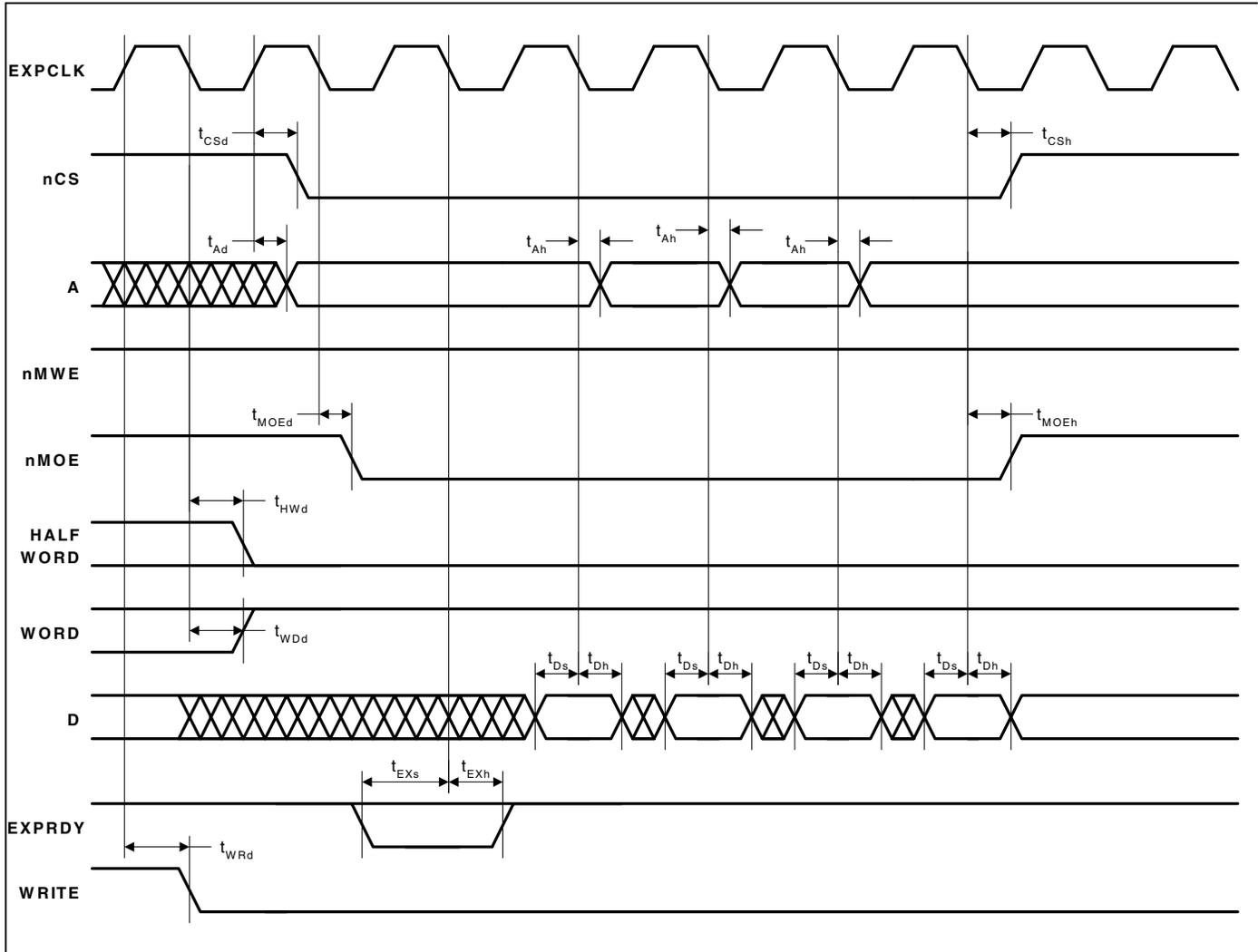


Figure 9. Static Memory Burst Read Cycle Timing Measurement

- Note:
1. Four cycles are shown in the above diagram (minimum wait states, 1-0-0-0). This is the maximum number of consecutive cycles that can be driven. The number of consecutive cycles can be programmed from 2 to 4, inclusively.
 2. The cycle time can be extended by integer multiples of the clock period (22 ns at 45 MHz, 27 ns at 36 MHz, 54 ns at 18.432 MHz, and 77 ns at 13 MHz), by either driving EXPRDY low and/or by programming a number of wait states. EXPRDY is sampled on the falling edge of EXPCLK before the data transfer. If low at this point, the transfer is delayed by one clock period where EXPRDY is sampled again. EXPCLK need not be referenced when driving EXPRDY, but is shown for clarity.
 3. Consecutive reads with sequential access enabled are identical except that the sequential access wait state field is used to determine the number of wait states, and no idle cycles are inserted between successive non-sequential ROM/expansion cycles. This improves performance so the SQAEN bit should always be set where possible.
 4. Address, Halfword, Word, and Write hold state until next cycle.

JTAG Interface

Parameter	Symbol	Min	Max	Units
TCK clock period	t_{clk_per}	2	-	ns
TCK clock high time	t_{clk_high}	1	-	ns
TCK clock low time	t_{clk_low}	1	-	ns
JTAG port setup time	t_{JPs}	-	0	ns
JTAG port hold time	t_{JPh}	-	3	ns
JTAG port clock to output	t_{JPco}	-	10	ns
JTAG port high impedance to valid output	t_{JPzx}	-	12	ns
JTAG port valid output to high impedance	t_{JPxz}	-	19	ns

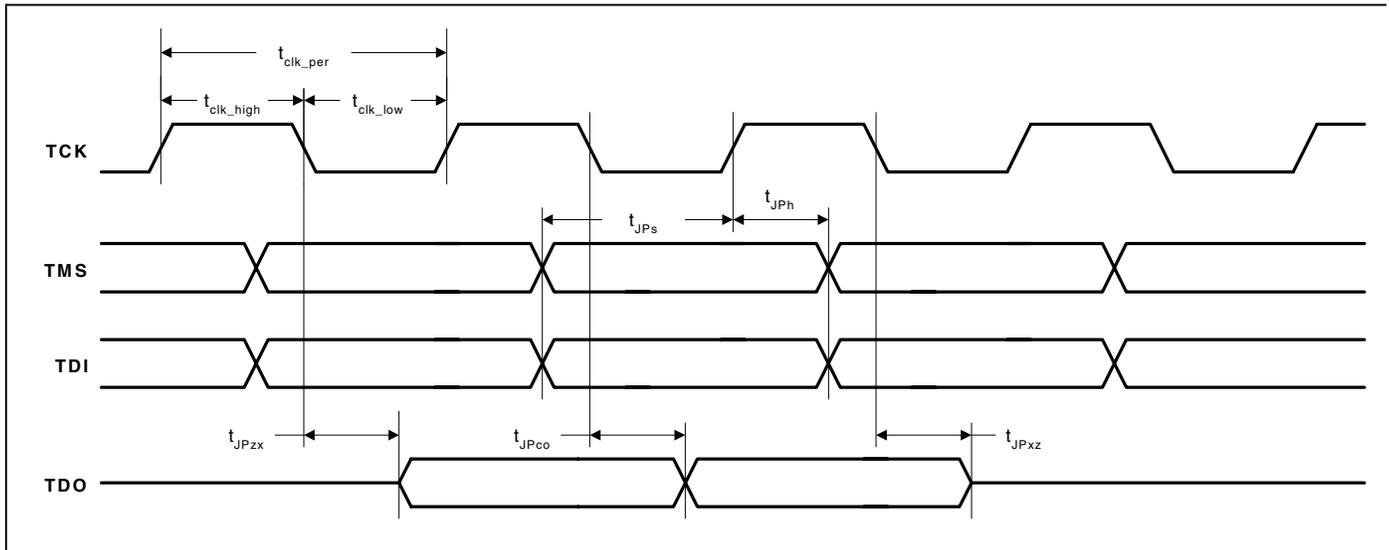
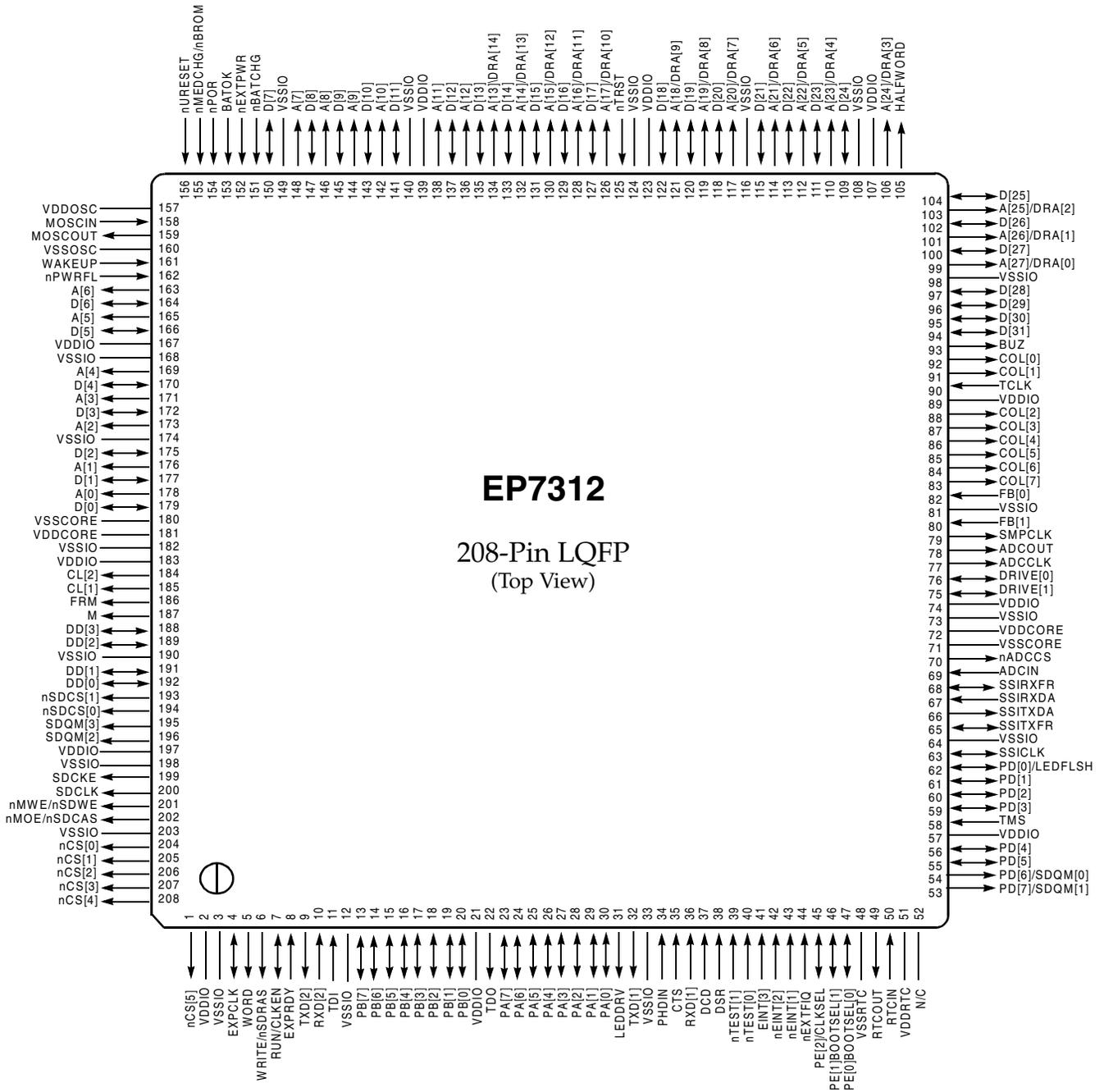


Figure 14. JTAG Timing Measurement

208-Pin LQFP Pin Diagram



208-Pin LQFP Numeric Pin Listing

Table 20. 208-Pin LQFP Numeric Pin Listing

Pin No.	Signal	Strength †	Reset State	Type	Description
1	nCS[5]	1	Low	O	Chip select 5
2	VDDIO			Pad Pwr	Digital I/O power, 3.3 V
3	VSSIO			Pad Gnd	I/O ground
4	EXPCLK	1		I	Expansion clock input
5	WORD	1	Low	O	Word access select output
6	WRITE/nSDRAS	1	Low	O	Transfer direction / SDRAM RAS signal output
7	RUN/CLKEN	1	Low	O	Run output / clock enable output
8	EXPRDY	1		I	Expansion port ready input
9	TXD[2]	1	High	O	UART 2 transmit data output
10	RXD[2]			I	UART 2 receive data input
11	TDI	with p/u*		I	JTAG data input
12	VSSIO			Pad Gnd	I/O ground
13	PB[7]	1	Input †	I/O	GPIO port B
14	PB[6]	1	Input †	I/O	GPIO port B
15	PB[5]	1	Input †	I/O	GPIO port B
16	PB[4]	1	Input †	I/O	GPIO port B
17	PB[3]	1	Input †	I/O	GPIO port B
18	PB[2]	1	Input †	I/O	GPIO port B
19	PB[1]	1	Input †	I/O	GPIO port B
20	PB[0]	1	Input †	I/O	GPIO port B
21	VDDIO			Pad Pwr	Digital I/O power, 3.3 V
22	TDO	1	Input †	O	JTAG data out
23	PA[7]	1	Input †	I/O	GPIO port A
24	PA[6]	1	Input †	I/O	GPIO port A
25	PA[5]	1	Input †	I/O	GPIO port A
26	PA[4]	1	Input †	I/O	GPIO port A
27	PA[3]	1	Input †	I/O	GPIO port A
28	PA[2]	1	Input †	I/O	GPIO port A
29	PA[1]	1	Input †	I/O	GPIO port A
30	PA[0]	1	Input †	I/O	GPIO port A
31	LEDDRV	1	Low	O	IR LED drive
32	TXD[1]	1	High	O	UART 1 transmit data out
33	VSSIO	1	High	Pad Gnd	I/O ground
34	PHDIN			I	Photodiode input
35	CTS			I	UART 1 clear to send input
36	RXD[1]			I	UART 1 receive data input
37	DCD			I	UART 1 data carrier detect

Table 20. 208-Pin LQFP Numeric Pin Listing (Continued)

Pin No.	Signal	Strength †	Reset State	Type	Description
118	D[20]	1	Low	I/O	Data I/O
119	A[19]/DRA[8]	1	Low	O	System byte address / SDRAM address
120	D[19]	1	Low	I/O	Data I/O
121	A[18]/DRA[9]	1	Low	O	System byte address / SDRAM address
122	D[18]	1	Low	I/O	Data I/O
123	VDDIO			Pad Pwr	Digital I/O power, 3.3 V
124	VSSIO			Pad Gnd	I/O ground
125	nTRST			I	JTAG async reset input
126	A[17]/DRA[10]	1	Low	O	System byte address / SDRAM address
127	D[17]	1	Low	I/O	Data I/O
128	A[16]/DRA[11]	1	Low	O	System byte address / SDRAM address
129	D[16]	1	Low	I/O	Data I/O
130	A[15]/DRA[12]	1	Low	O	System byte address / SDRAM address
131	D[15]	1	Low	I/O	Data I/O
132	A[14]/DRA[13]	1	Low	O	System byte address / SDRAM address
133	D[14]	1	Low	I/O	Data I/O
134	A[13]/DRA[14]	1	Low	O	System byte address / SDRAM address
135	D[13]	1	Low	I/O	Data I/O
136	A[12]	1	Low	O	System byte address
137	D[12]	1	Low	I/O	Data I/O
138	A[11]	1	Low	O	System byte address
139	VDDIO			Pad Pwr	Digital I/O power, 3.3 V
140	VSSIO			Pad Gnd	I/O ground
141	D[11]	1	Low	I/O	Data I/O
142	A[10]	1	Low	O	System byte address
143	D[10]	1	Low	I/O	Data I/O
144	A[9]	1	Low	O	System byte address
145	D[9]	1	Low	I/O	Data I/O
146	A[8]	1	Low	O	System byte address
147	D[8]	1	Low	I/O	Data I/O
148	A[7]	1	Low	O	System byte address
149	VSSIO			Pad Gnd	I/O ground
150	D[7]	1	Low	I/O	Data I/O
151	nBATCHG			I	Battery changed sense input
152	nEXTPWR			I	External power supply sense input
153	BATOK			I	Battery OK input
154	nPOR	Schmitt		I	Power-on reset input
155	nMEDCHG/nBROM			I	Media change interrupt input / internal ROM boot enable
156	nURESET	Schmitt		I	User reset input
157	VDDOSC			Oscillator Power	Oscillator power in, 2.5 V
158	MOSCIN			I	Main oscillator input
159	MOSCOUT			O	Main oscillator output
160	VSSOSC			Oscillator Ground	Oscillator Ground

Table 20. 208-Pin LQFP Numeric Pin Listing (Continued)

Pin No.	Signal	Strength †	Reset State	Type	Description
206	nCS[2]	1	High	O	Chip select 2
207	nCS[3]	1	High	O	Chip select 3
208	nCS[4]	1	High	O	Chip select 4

* "With p/u" means with internal pull-up of 100 KOHms on the pin.

† Strength 1 = 4 ma

Strength 2 = 12 ma

‡ Input. Port A,B,D,E GPIOs default to input at nPOR and URESET conditions.

204-Ball TFBGA Package Characteristics

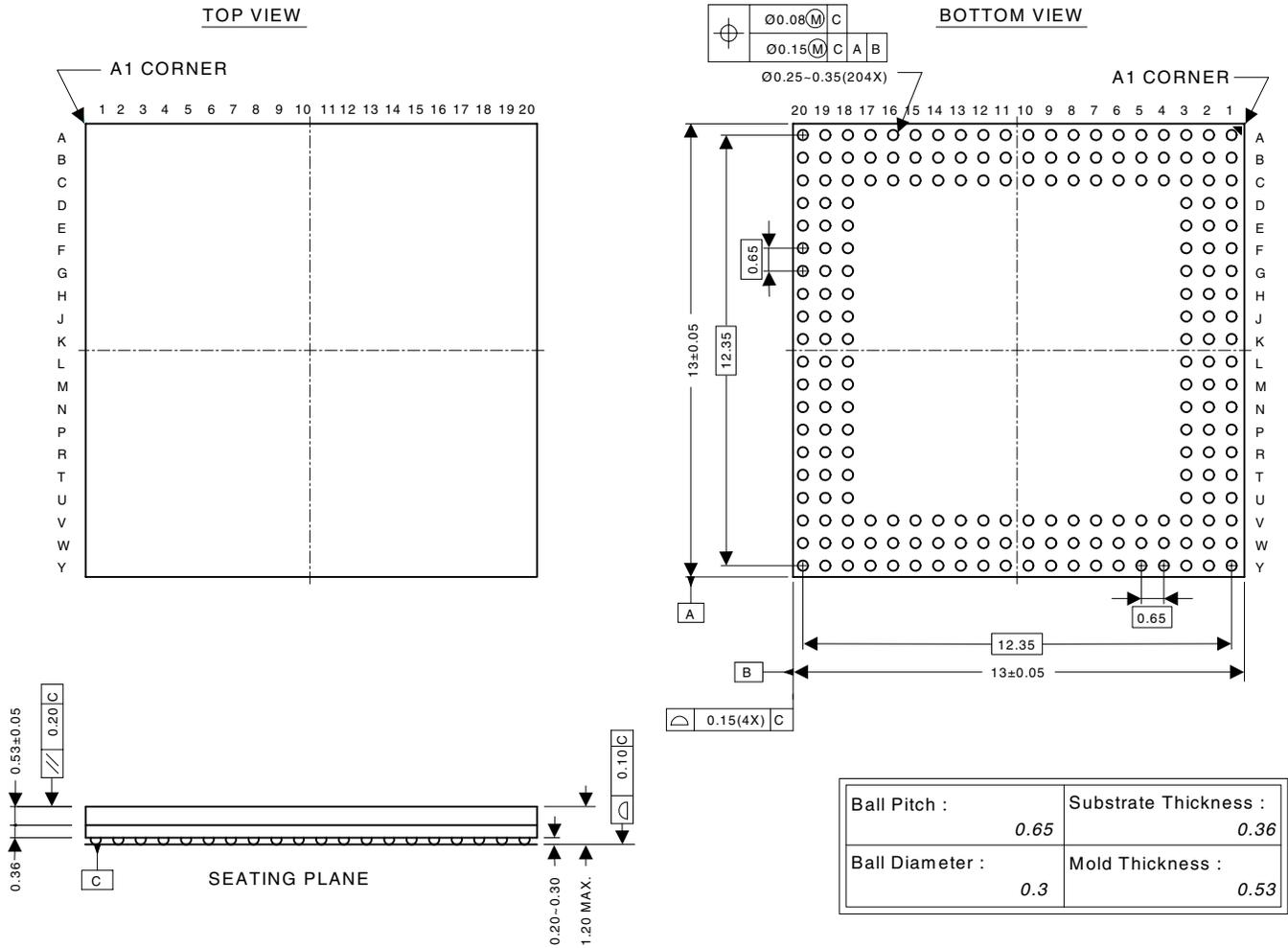


Figure 17. 204-Ball TFBGA Package

Table 21. 204-Ball TFBGA Ball Listing (Continued)

Ball Location	Name	Strength [†]	Reset State	Type	Description
B8	DD[1]	1	Low	O	LCD serial display data
B9	M	1	Low	O	LCD AC bias drive
B10	CL[2]	1	Low	O	LCD pixel clock out
B11	D[0]	1	Low	I/O	Data I/O
B12	A[1]	2	Low	O	System byte address
B13	D[3]	2	Low	I/O	Data I/O
B14	A[4]	1	Low	O	System byte address
B15	D[6]	1	Low	I/O	Data I/O
B16	WAKEUP	Schmitt		I	System wake up input
B17	MOSCIN			I	Main oscillator input
B18	VSSIO			Pad ground	I/O ground
B19	VSSIO			Pad ground	I/O ground
B20	nURESET	Schmitt		I	User reset input
C1	RUN/CLKEN	1	Low	O	Run output / clock enable output
C2	EXPRDY	1		I	Expansion port ready input
C3	VDDIO			Pad power	Digital I/O power, 3.3 V
C4	nCS[4]	1	High	O	Chip select 4
C5	nCS[0]	1	High	O	Chip select 0
C6	SDCLK	2	Low	O	SDRAM clock out
C7	SDQM[3]	2	Low	O	SDRAM byte lane mask
C8	DD[0]	1	Low	O	LCD serial display data
C9	DD[3]	1	Low	O	LCD serial display data
C10	VDDCORE			Core power	Digital core power, 2.5 V
C11	A[0]	2	Low	O	System byte address
C12	D[2]	1	Low	I/O	Data I/O
C13	A[3]	2	Low	O	System byte address
C14	D[5]	1	Low	I/O	Data I/O
C15	A[6]	1	Low	O	System byte address
C16	VSSOSC			Oscillator ground	PLL ground
C17	VDDOSC			Oscillator power	Oscillator power in, 2.5V
C18	VSSIO			Pad ground	I/O ground
C19	BATOK			I	Battery ok input

Table 21. 204-Ball TFBGA Ball Listing (Continued)

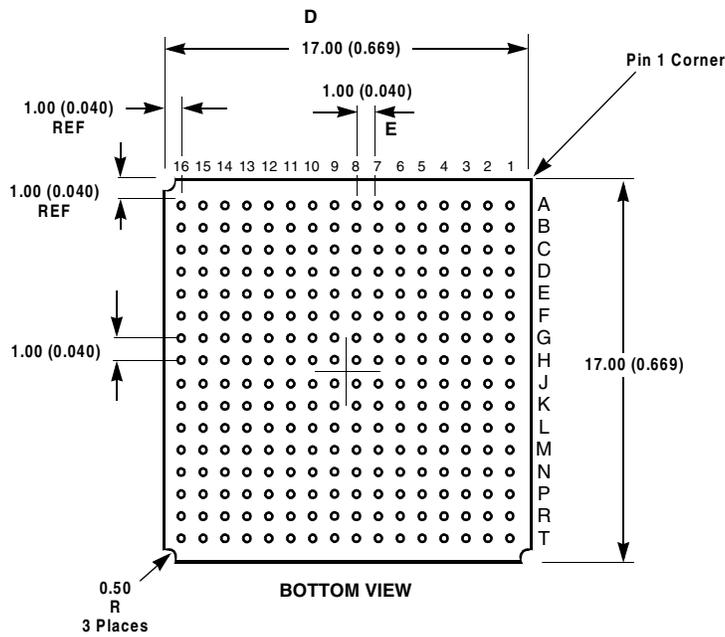
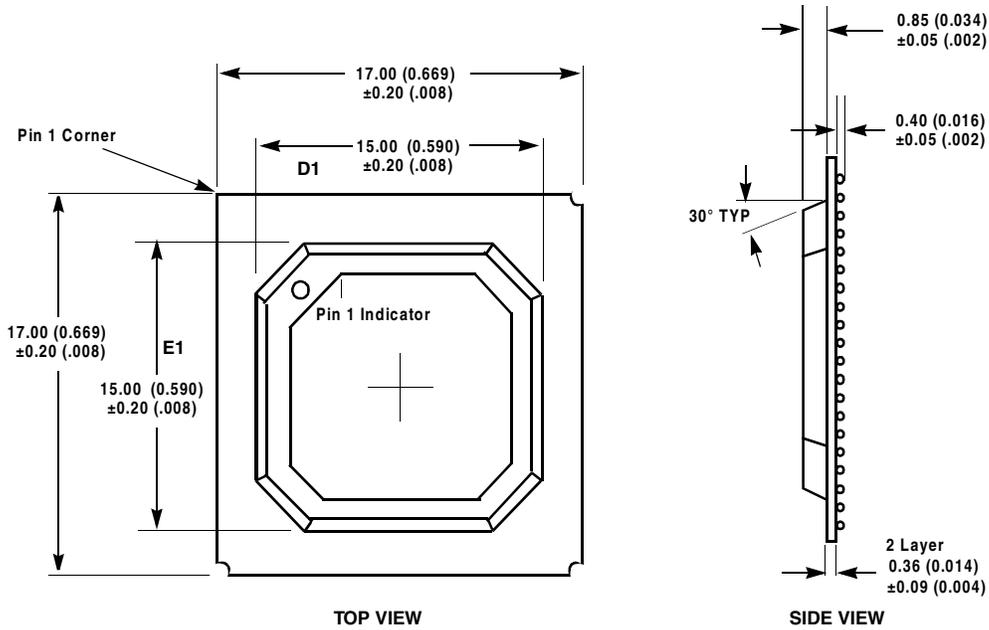
Ball Location	Name	Strength [†]	Reset State	Type	Description
C20	nPOR	Schmitt		I	Power-on reset input
D1	PB[7]	1	Input [†]	I	GPIO port B
D2	RXD[2]			I	UART 2 receive data input
D3	VDDIO			Pad power	Digital I/O power, 3.3V
D18	VSSIO			Pad ground	I/O ground
D19	nBATCHG			I	Battery changed sense input
D20	A[7]	1	Low	O	System byte address
E1	PB[4]	1	Input [†]	I	GPIO port B
E2	TXD[2]	1	High	O	UART 2 transmit data output
E3	WRITE/nSDRAS	1	Low	O	Transfer direction / SDRAM RAS signal output
E18	nMEDCHG/nBROM			I	Media change interrupt input / internal ROM boot enable
E19	nEXTPWR			I	External power supply sense input
E20	D[9]	1	Low	I/O	Data I/O
F1	PB[3]	1	Input [†]	I/O	GPIO port B
F2	PB[6]	1	Input [†]	I/O	GPIO port B
F3	TDI	with p/u*		I	JTAG data input
F18	D[7]	1	Low	I/O	Data I/O
F19	A[8]	1	Low	O	System byte address
F20	D[10]	1	Low	I/O	Data I/O
G1	PB[1]	1	Input [†]	I/O	
G2	PB[2]	1	Input [†]	I/O	GPIO port B
G3	PB[5]	1	Input [†]	I/O	GPIO port B
G18	D[8]	1	Input [†]	I/O	Data I/O
G19	A[9]	1	Low	O	System byte address
G20	D[11]	1	Low	I/O	Data I/O
H1	PA[7]	1	Input [†]	I/O	GPIO port A
H[2]	TDO	1	Input [†]	O	JTAG data out
H[3]	PB[0]	1	Input [†]	I/O	GPIO port B
H[18]	A[10]	1	Low	O	System byte address

Table 21. 204-Ball TFBGA Ball Listing (Continued)

Ball Location	Name	Strength [†]	Reset State	Type	Description
H19	D[12]	1	Low	I/O	Data I/O
H20	A[12]	1	Low	O	System byte address
J1	PA[4]	1	Input [‡]	I/O	GPIO port A
J2	PA[5]	1	Input [‡]	I/O	GPIO port A
J3	PA[6]	1	Input [‡]	I/O	GPIO port A
J18	A[11]	1	Low	O	System byte address
J19	D[13]	1	Low	I/O	Data I/O
J20	A[13]/DRA[14]	1	Low	O	System byte address / SDRAM address
K1	PA[1]	1	Input [‡]	I/O	GPIO port A
K2	PA[2]	1	Input [‡]	I/O	GPIO port A
K3	VDDIO			Pad power	Digital I/O power, 3.3V
K18	D[14]	1	Low	I/O	Data I/O
K19	A[14]/DRA[13]	1	Low	O	System byte address / SDRAM address
K20	D[15]	1	Low	I/O	Data I/O
L1	TXD[1]	1	High	O	UART 1 transmit data out
L2	LEDDRV	1	Low	O	IR LED drive
L3	PA[3]	1	Input [‡]	I/O	GPIO port A
L18	VDDIO			Pad power	Digital I/O power, 3.3V
L19	D[16]	1	Low	I/O	Data I/O
L20	A[16]/DRA[11]	1	Low	O	System byte address / SDRAM address
M1	RXD[1]			I	UART 1 receive data input
M2	CTS			I	UART 1 clear to send input
M3	PA[0]	1	Input [‡]	I/O	GPIO port A
M18	A[15]/DRA[12]	1	Low	O	System byte address / SDRAM address
M19	A[17]/DRA[10]	1	Low	O	System byte address / SDRAM address
M20	nTRST			I	JTAG async reset input
N1	DSR			I	UART 1 data set ready input
N2	nTEST[1]	With p/u*		I	Test mode select input
N3	PHDIN			I	Photodiode input

Table 21. 204-Ball TFBGA Ball Listing (Continued)

Ball Location	Name	Strength [†]	Reset State	Type	Description
V2	VSSIO			Pad ground	I/O ground
V3	VSSIO			Pad ground	I/O ground
V4	PD[7]/SDQM[1]	1	Low	I/O	GPIO port D / SDRAM byte lane mask
V5	PD[4]	1	Low	I/O	GPIO port D
V6	PD[2]	1	Low	I/O	GPIO port D
V7	SSICLK	1	Input [‡]	I/O	DAI/CODEC/SSI2 serial clock
V8	SSIRXDA			I/O	DAI/CODEC/SSI2 serial data input
V9	nADCCS	1	High	O	SSI1 ADC chip select
V10	VDDIO			Pad power	Digital I/O power, 3.3V
V11	ADCCLK	1	Low	O	SSI1 ADC serial clock
V12	COL[7]	1	High	O	Keyboard scanner column drive
V13	COL[4]	1	High	O	Keyboard scanner column drive
V14	TCLK			I	JTAG clock
V15	BUZ	1	Low	O	Buzzer drive output
V16	D[29]	1	Low	I/O	Data I/O
V17	A[26]/DRA[1]	2	Low	O	System byte address / SDRAM address
V18	VDDIO			Pad power	Digital I/O power, 3.3 V
V19	VDDIO			Pad power	Digital I/O power, 3.3 V
V20	A[24]/DRA[3]	1	Low	O	System byte address / SDRAM address
W1	VSSIO			Pad ground	I/O ground
W2	VSSIO			Pad ground	I/O ground
W3	VSSIO			Pad ground	I/O ground
W4	PD[6]/SDQM[0]	1	Low	I/O	GPIO port D / SDRAM byte lane mask
W5	TMS	with p/u*		I	JTAG mode select
W6	PD[1]	1	Low	I/O	GPIO port D
W7	SSITXFR	1	Low	I/O	DAI/CODEC/SSI2 frame sync
W8	SSIRXFR	1	Input [‡]	I/O	DAI/CODEC/SSI2 frame sync
W9	VSSCORE			Core Ground	Core Ground
W10	DRIVE[1]	2	High / Low	I/O	PWM drive output



JEDEC #: MO-151
Ball Diameter: 0.50 mm ± 0.10 mm
17 ¥ 17 ¥ 1.61 mm body

Table 22. 256-Ball PBGA Ball Listing (Continued)

Ball Location	Name	Strength †	Reset State	Type	Description
F10	D[6]	1	Low	I/O	Data I/O
F11	VSSRTC			RTC ground	Real time clock ground
F12	BATOK			I	Battery OK input
F13	nBATCHG			I	Battery changed sense input
F14	VSSIO			Pad ground	I/O ground
F15	D[11]	1	Low	I/O	Data I/O
F16	VDDIO			Pad power	Digital I/O power, 3.3V
G1	PB[1]	1	Input †	I	GPIO port B
G2	VDDIO			Pad power	Digital I/O power, 3.3V
G3	TDO	1	Input †	O	JTAG data out
G4	PB[4]	1	Input †	I	GPIO port B
G5	PB[6]	1	Input †	I	GPIO port B
G6	VSSCore			Core ground	Core ground
G7	VSSRTC			RTC ground	Real time clock ground
G8	DD[0]	1	Low	O	LCD serial display data
G9	D[3]	1	Low	I/O	Data I/O
G10	VSSRTC			RTC ground	Real time clock ground
G11	A[7]	1	Low	O	System byte address
G12	A[8]	1	Low	O	System byte address
G13	A[9]	1	Low	O	System byte address
G14	VSSIO			Pad ground	I/O ground
G15	D[12]	1	Low	I/O	Data I/O
G16	D[13]	1	Low	I/O	Data I/O
H1	PA[7]	1	Input †	I/O	GPIO port A
H2	PA[5]	1	Input †	I/O	GPIO port A
H3	VSSIO			Pad ground	I/O ground
H4	PA[4]	1	Input †	I/O	GPIO port A
H5	PA[6]	1	Input †	I/O	GPIO port A
H6	PB[0]	1	Input †	I/O	GPIO port B
H7	PB[2]	1	Input †	I/O	GPIO port B
H8	VSSRTC			RTC ground	Real time clock ground
H9	VSSRTC			RTC ground	Real time clock ground
H10	A[10]	1	Low	O	System byte address
H11	A[11]	1	Low	O	System byte address
H12	A[12]	1	Low	O	System byte address
H13	A[13]/DRA[14]	1	Low	O	System byte address / SDRAM address
H14	VSSIO			Pad ground	I/O ground
H15	D[14]	1	Low	I/O	Data I/O
H16	D[15]	1	Low	I/O	Data I/O
J1	PA[3]	1	Input †	I/O	GPIO port A
J2	PA[1]	1	Input †	I/O	GPIO port A
J3	VSSIO			Pad ground	I/O ground
J4	PA[2]	1	Input †	I/O	GPIO port A

Table 23. JTAG Boundary Scan Signal Ordering (Continued)

LQFP Pin No.	TFBGA Ball	PBGA Ball	Signal	Type	Position
110	U20	M13	A[23]/DRA[4]	O	194
111	T19	N16	D[23]	I/O	196
112	T20	L12	A[22]/DRA[5]	O	199
113	R19	N15	D[22]	I/O	201
114	R20	L13	A[21]/DRA[6]	O	204
115	T18	M16	D[21]	I/O	206
117	P19	M15	A[20]/DRA[7]	O	209
118	P20	K11	D[20]	I/O	211
119	R18	L16	A[19]/DRA[8]	O	214
120	N19	K12	D[19]	I/O	216
121	N20	L15	A[18]/DRA[9]	O	219
122	P18	K13	D[18]	I/O	221
126	M19	J10	A[17]/DRA[10]	O	224
127	N18	J16	D[17]	I/O	226
128	L20	J11	A[16]/DRA[11]	O	229
129	L19	J15	D[16]	I/O	231
130	M18	J12	A[15]/DRA[12]	O	234
131	K20	H16	D[15]	I/O	236
132	K19	J13	A[14]/DRA[13]	O	239
133	K18	H15	D[14]	I/O	241
134	J20	H13	A[13]/DRA[14]	O	244
135	J19	G16	D[13]	I/O	246
136	H20	H12	A[12]	O	249
137	H19	G15	D[12]	I/O	251
138	J18	H11	A[11]	O	254
141	G20	F15	D[11]	I/O	256
142	H18	H10	A[10]	O	259
143	F20	E16	D[10]	I/O	261
144	G19	G13	A[9]	O	264
145	E20	E15	D[9]	I/O	266
146	F19	G12	A[8]	O	269
147	G18	D16	D[8]	I/O	271
148	D20	G11	A[7]	O	274
150	F18	D15	D[7]	I/O	276
151	D19	F13	nBATCHG	I	279
152	E19	C16	nEXTPWR	I	280
153	C19	F12	BATOK	I	281
154	C20	C15	nPOR	I	282

Table 23. JTAG Boundary Scan Signal Ordering (Continued)

LQFP Pin No.	TFBGA Ball	PBGA Ball	Signal	Type	Position
206	B4	D5	nCS[2]	O	366
207	A3	B3	nCS[3]	O	368
208	C4	A2	nCS[4]	O	370

- 1) See EP7312 Users' Manual for pin naming / functionality.
- 2) For each pad, the JTAG connection ordering is input, output, then enable as applicable.